```
Chap1电磁现象的普遍规律
库仑定律F = Q'E = \frac{QQ'\hat{r}}{4\pi\varepsilon_0 r^2}
                                                            电场叠加性E=\sum_{i=1}^n rac{Q_i\hat{r}_i}{4\piarepsilon_0 r_i^2}=\int_V rac{
ho(m{x}')m{r}dV'}{4\piarepsilon_0 r^3}
高斯定理&电场散度 \oint_S m{E} \cdot dm{S} = \frac{1}{arepsilon_0} \sum_i Q_i = \frac{1}{arepsilon_0} \int_V 
ho dV 或 \nabla \cdot m{E} = \frac{
ho}{arepsilon_0}
静电场旋度
abla	imes m{E} = 0 电荷守恒定律\oint_S m{J} \cdot dm{S} = -\int_V rac{\partial 
ho}{\partial t} dV 或 
abla \cdot m{J} + rac{\partial 
ho}{\partial t} = 0
毕奥-萨伐尔定律m{B}(m{x}) = rac{\mu_0}{4\pi} \int_V rac{J(m{x}') 	imes r}{r^3} dV' = rac{\mu_0}{4\pi} \oint_L rac{Idl 	imes r}{r^3} 磁场环量&旋度\oint_L m{B} \cdot dm{l} = \mu_0 I = \mu_0 \int_S m{J} \cdot dm{S} \ \ \ \ \ \ \nabla 	imes m{B} = \mu_0 m{J}
电磁感应定律\mathscr{E}=\oint_L m{E}\cdot dm{l}=-rac{d}{dt}\int_S m{B}\cdot dm{S} 或 
abla	imesm{E}=-rac{\partial B}{\partial t}
位移电流J_D = \varepsilon \frac{\partial E}{\partial t} \Rightarrow \nabla \times B = \mu (J + J_D)
介质的极化 电极化强度矢量m{P}=rac{\sum_{m{i}}m{p_i}}{\Delta V} 其中电偶极矩m{p}=qm{l},m{l}由负指向正电荷
        束缚电荷密度\int_V 
ho_P dV = -\oint_S m{P} \cdot dm{S} 或 
ho_P = - 
abla \cdot m{P}
        介质分界面束缚电荷面密度\sigma_P = -m{e}_n \cdot (m{P}_2 - m{P}_1) 其中m{e}_n由介质1指向2
        高斯定理\varepsilon_0 \nabla \cdot \boldsymbol{E} = \rho_f + \rho_P \Rightarrow \nabla \cdot (\varepsilon_0 \boldsymbol{E} + \boldsymbol{P}) = \rho_f
        电位移矢量\mathbf{D} = \varepsilon_0 \mathbf{E} + \mathbf{P} 故 \nabla \mathbf{D} = \rho_f
        对各向同性线性介质P = \chi_e \varepsilon_0 \mathbf{E} 故 \mathbf{D} = \varepsilon \mathbf{E}
                其中\chi_e-极化率,\varepsilon=\varepsilon_r\varepsilon_0-电容率,\varepsilon_r=1+\chi_e-相对电容率
        对各向异性介质D_i = \sum_{j=1}^3 \varepsilon_{ij} E_j
        \mathbb{R}^{3} 强场下介质非线性D_i=\sum_j arepsilon_{ij} E_j + \sum_{j,k} arepsilon_{ijk} E_j E_k + \sum_{jkl} arepsilon_{ijkl} E_j E_k E_l + \cdots的磁化 分子电流磁矩m=ia 其中i—分子电流,a—分子电流环绕面积
介质的磁化 分子电流磁矩m{m}=im{a}
```

磁化强度 $m{M}=rac{\sum_i m{m}_i}{\Delta V}$ 磁化电流 $I_M=\oint_L m{M}\cdot dm{l}$ 磁化电流密度 $m{J}_M= abla imesm{M}$ 当电场变化时,介质的极化强度矢量 $\mathbf{P}=rac{\sum_{i}e_{i}\mathbf{x}_{i}}{\Delta V}(\Delta V$ 中各带电粒子位置为 \mathbf{x}_{i} ,电荷为 e_{i})变化,产生极化

Chap2静电场

定义电势 $E = -\nabla \varphi$

点电荷在距离r处的电势 $\varphi=\frac{Q}{4\pi\varepsilon_0 r}$ 电势叠加 $\varphi=\sum_i rac{Q}{4\piarepsilon_0 r_i}=\int_V rac{
ho(m{x}')dV'}{4\piarepsilon_0 r}$ 泊松方程(均匀各向同性线性介质) $abla^2 \varphi = -\frac{\rho}{\varepsilon}$ 边值关系 $\varphi_1 = \varphi_2, \varepsilon_2 \frac{\partial \varphi_1}{\partial n} - \varepsilon_1 \frac{\partial \varphi_1}{\partial n} = -\sigma_f$ 唯一性定理 区域V内给定自由电荷分布 $ho(m{x})$,V的边界S上给定 1. 电势 $arphi|_S$ 或 2. 电势的法线方向偏导数 $rac{\partial arphi}{\partial n}|_S$, 则V内电场唯一地确定 有导体存在时的唯一性定理 区域V内有一些导体,给定去除导体后的区域V'内的电荷密度ho,给定 各导体上电势 $arphi_i$ 或各导体上总电荷 Q_i ,且给定V的外边界S上的 $arphi_S$ 或 $\frac{\partial arphi}{\partial n}|_S$,则V'内电场唯一地确定 若区域V内无自由电荷ho=0,泊松方程化为**拉普拉斯方程** $abla^2arphi=0$

分离变量法 直角坐标系 $\varphi(x,y,z)=X(x)Y(y)Z(z)\Rightarrow rac{1}{X}rac{d^2X}{dx^2}+rac{1}{Y}rac{d^2Y}{dy^2}=-rac{1}{Z}rac{d^2Z}{dz^2}$ 设 $\frac{1}{X}\frac{d^2X}{dx^2} = -\alpha^2$, $\frac{1}{Y}\frac{d^2Y}{dy^2} = -\beta^2$, $\frac{1}{Z}\frac{d^2Z}{dz^2} = \gamma^2$ 其中 $\gamma^2 = \alpha^2 + \beta^2$ 通解为 $X(x) = \operatorname{Re}(A_{\alpha}e^{i\alpha x} + B_{\alpha}e^{-i\alpha x})$, $Y(y) = \operatorname{Re}(A_{\beta}e^{i\beta y} + B_{\beta}e^{-i\beta y})$, $Z(z) = \operatorname{Re}(A_{\gamma}e^{i\gamma z} + B_{\gamma}e^{-i\gamma z})$

柱坐标系 通解为 $\varphi(r,\theta) = \sum_{n=1}^{\infty} [r^n (A_n \cos n\theta + B_n \sin n\theta) + r^{-n} (C_n \cos n\theta + D_n \sin n\theta)]$ 若轴对称,则为 $\varphi(r) = A + B \ln r$

球坐标系 通解为 $\varphi(R, heta,arphi) \; = \; \sum_{n,m} (a_{nm}R^n \; + \; rac{b_n m}{R^{n+1}}) P_n^m(\cos heta) \cos marphi \; + \; \sum_{n,m} (c_{nm}R^n \; + \; c_{nm}) P_n^m(\cos heta) + \sum_{n,m} (c_{nm}R^n \; +$ $rac{d_{nm}}{R^{n+1}})P_n^m(\cos heta)\sin m arphi$ 若有对称轴且以之为极轴,则 $arphi=\sum_n(a_nR^n+rac{b_n}{R^{n+1}})P_n(\cos heta)$ 其中低阶勒氏多项式: 低阶连带勒氏多项式:

$$\begin{array}{l} P_{0}(x) = 1 \\ P_{1}(x) = x \\ P_{2}(x) = \frac{1}{2}(3x^{2} - 1) \\ P_{3}(x) = \frac{1}{8}(5x^{3} - 3x) \\ P_{4}(x) = \frac{1}{8}(35x^{4} \\ -30x^{2} + 3) \\ P_{5}(x) = \frac{1}{8}(63x^{5} \\ -70x^{3} + 15x) \end{array} \quad \begin{array}{l} P_{0}^{1}(x) = P_{0}^{1}(x) \\ P_{1}^{1}(x) = \sqrt{1 - x^{2}} \\ P_{1}^{2}(x) = 3x\sqrt{1 - x^{2}} \\ P_{2}^{2}(x) = 3(1 - x^{2}) \\ P_{2}^{2}(x) = 3(1 - x^{2}) \\ P_{3}^{3}(x) = \frac{3}{2}(1 - x^{2})^{\frac{1}{2}}(5x^{2} - 1) \\ P_{3}^{3}(x) = \frac{3}{2}(1 - x^{2})^{\frac{1}{2}}(5x^{2} - 1) \\ P_{3}^{3}(x) = 15(1 - x^{2})x \\ P_{3}^{3}(x) = 15(1 - x^{2})^{\frac{3}{2}} \end{array} \quad \begin{array}{l} P_{1}^{-1}(x) = -\frac{1}{2}\sqrt{1 - x^{2}} \\ P_{1}^{-1}(x) = -\frac{1}{2}\sqrt{1 - x^{2}} \\ P_{2}^{-1}(x) = -\frac{1}{2}x\sqrt{1 - x^{2}} \\ P_{2}^{-1}(x) =$$

接地无限大平面导体板附近有一点电荷Q,镜像电荷Q'=-Q位于点电荷关于导体板对称的位置,电势 $arphi=rac{1}{4\piarepsilon_0}(rac{Q}{r}-$

Chap3静磁场

定义矢势 $B = \nabla \times A$ 故 $\int_S B \cdot dS = \oint_L A \cdot dl$ 库伦规范 $\nabla^2 \mathbf{A} = -\mu_0 \mathbf{J}, \nabla \cdot \mathbf{A} = 0$ 下, $\mathbf{A}(\mathbf{x}) = \frac{\mu_0}{4\pi} \int_V \frac{\mathbf{J}(\mathbf{x}')}{r} dV'$ 边值关系 $m{A}_1 = m{A}_2, m{e}_n imes (rac{1}{\mu_2}
abla imes m{A}_2 - rac{1}{\mu_1}
abla imes m{A}_1)$ 定义磁标势 $m{H}=ablaarphi_m$ 和假想磁荷密度 $ho_m=-\mu_0
abla\cdotm{M}$ 得磁标势方程 $abla^2arphi_m=-rac{
ho_m}{\mu_0}$ 边值关系 $e_n \times (-\nabla \varphi_2 + \nabla \varphi_1) = \alpha_f, B_{2n} = B_{1n}$ 对线性均匀介质,且界面上 $\alpha_f = 0$,有 $\varphi_2 = \varphi_1, \mu_2 \frac{\partial \varphi_2}{\partial n} = \mu_1 \frac{\partial \varphi_1}{\partial n}$ 磁标势法用静电场类比静磁场

$$\begin{cases} \nabla \times \mathbf{E} = 0 & \nabla \times \mathbf{H} = 0 \\ \nabla \cdot \mathbf{E} = \frac{(\rho_f + \rho_P)}{\varepsilon_0} & \nabla \cdot \mathbf{H} = \frac{\rho_m}{\mu_0} \\ \rho_P = -\nabla \cdot \mathbf{P} & \rho_m = -\mu_0 \nabla \cdot \mathbf{M} \end{cases} \begin{cases} D = \varepsilon_0 \mathbf{E} + \mathbf{P} & B = \mu_0 \mathbf{H} + \mu_0 \mathbf{M} \\ E = -\nabla \varphi & \mathbf{H} = -\nabla \varphi_m \\ \nabla^2 \varphi = -\frac{(\rho_f + \rho_P)}{\varepsilon_0} & \nabla^2 \varphi_m = -\frac{\rho_m}{\mu_0} \end{cases}$$

Chap4电磁波的传播

真空中的波动方程 取麦氏方程组第一式旋度并利用第二、三式得 $abla^2 E - rac{1}{c^2} rac{\partial^2 E}{\partial t^2} = 0$ 取第二式旋度并利用第一、四式得 $\nabla^2 B - \frac{1}{c^2} \frac{\partial^2 B}{\partial t^2} = 0$ 时谐电磁波 $m{E}(m{x},t) = m{E}(m{x})e^{-i\omega t}, m{B}(m{x},t) = m{B}(m{x})e^{-i\omega t}$

代入麦氏方程组得
$$\begin{cases} \nabla \times \mathbf{E} = i\omega \mu \mathbf{H} & \nabla \cdot \mathbf{E} = 0 \\ \nabla \times \mathbf{H} = -i\omega \varepsilon \mathbf{E} & \nabla \cdot \mathbf{H} = 0 \end{cases}$$
 可化为
$$\begin{cases} \nabla^2 \mathbf{E} + k^2 \mathbf{E} = 0 \\ \nabla \cdot \mathbf{E} = 0 \end{cases}$$
 或
$$\begin{cases} \nabla^2 \mathbf{B} + k^2 \mathbf{B} = 0 \\ \nabla \cdot \mathbf{B} = 0 \end{cases}$$
 其中 $k = \omega \sqrt{\mu \varepsilon}$
$$\mathbf{E} = \frac{i}{k \sqrt{\mu \varepsilon}} \nabla \times \mathbf{B}$$

其中折射率 $n = \sqrt{\mu_r \varepsilon_r}$ 线性均匀绝缘介质中单色波相速度 $v=\frac{c}{n}$

电磁波为横波, 电场方向(偏振方向)、磁场方向、传播方向两两正交, $\mathbf{k} \cdot \mathbf{E} = \mathbf{k} \cdot \mathbf{B} =$ $m{E} \cdot m{B} = 0$ 电磁场振幅比 $|rac{E}{B}| = rac{1}{\sqrt{\mu \varepsilon}} = v$

电磁场能量密度(线性均匀介质) $w=\frac{1}{2}(\varepsilon E^2+\frac{1}{\mu}B^2)=(\because$ 电磁场能量相等) $\varepsilon E^2=\frac{1}{\mu}B^2$ 能流密度 $S=E imes H=\sqrt{\frac{\varepsilon}{\mu}}E imes(e_k imes E)=\sqrt{\frac{\varepsilon}{\mu}}E^2e_k=\frac{1}{\sqrt{\mu\varepsilon}}we_k=vwe_k$ 能量密度平均值 $\bar{w}=\frac{1}{2}\varepsilon E_0^2=\frac{1}{2\mu}B_0^2$

能流密度平均值 $\bar{S}=rac{1}{2}\mathrm{Re}(m{E}^* imesm{H})=rac{1}{2}\sqrt{rac{arepsilon}{\mu}}E_0^2m{e}_k$

电磁波的反射与折射 在介质界面上仅需考虑 $\dot{m e}_n imes(m E_2-m E_1)=0, m e_n imes(m H_2-m H_1)=m lpha$

反射和折射定律 $\theta=\theta'$ $\frac{\sin\theta}{\sin\theta''}=\frac{v_1}{v_2}=\frac{\sqrt{\mu_2\varepsilon_2}}{\sqrt{\mu_1\varepsilon_1}}=\frac{n_2}{n_1}=n_{21}$ 菲涅尔公式 对E \bot 入射面(s偏振) $E+E'=E'',H'\cos\theta-H'\cos\theta'=H''\cos\theta''$

 \Rightarrow 非铁磁性介质 $\sqrt{\varepsilon_1}(E-E')\cos\theta=\sqrt{\varepsilon_2}E''\cos\theta''$ 结合折射定律得

电流密度 $J_P = \frac{\partial P}{\partial t} = \frac{\sum_i e_i v_i}{\Delta V}$,此时磁场旋度 $\frac{1}{\mu_0} \nabla \times B = J_f + J_M + J_P + \varepsilon_0 \frac{\partial E}{\partial t}$ 或 $\nabla \times (\frac{B}{\mu_0} - M) = J_f + \frac{\partial D}{\partial t}$ 定义磁场强度 $H = \frac{B}{\mu_0} - M$ 从而有 $\nabla \times H = J_f + \frac{\partial D}{\partial t}$

对各向同性非铁磁物质 $\mathbf{M} = \chi_M \mathbf{H} \Rightarrow \mathbf{B} = \mu \mathbf{H}$

其中 χ_M -磁化率, $\mu=\mu_r\mu_0$ -磁导率,相对磁导率 $\mu_r=1+\chi_M$

对铁磁性物质,B与H的关系依赖于磁化过程,常用磁化曲线和磁滞回线表示

麦克斯韦方程组 $\nabla \cdot \boldsymbol{D} = \rho$ $\oint_S \mathbf{D} \cdot d\mathbf{S} = Q_f$ $\nabla \cdot \boldsymbol{B} = 0$ $\oint_{S} \cdot d\mathbf{S} = 0$

洛伦兹力密度 $\mathbf{f} = \rho \mathbf{E} + \mathbf{J} \times \mathbf{B}$ 点电荷受洛伦兹力 $\mathbf{F} = q \mathbf{E} + q \mathbf{v} \times \mathbf{B}$ 欧姆定律 $J = \sigma \mathbf{E}$ $\boldsymbol{e}_n \cdot (D_2 + D_1 = \sigma_f \qquad \boldsymbol{e}_n \times (\boldsymbol{E}_2 - \boldsymbol{E}_1) = 0$ 边值关系 $\left\{ egin{array}{ccc} oldsymbol{e}_n\cdot(oldsymbol{B}_2-oldsymbol{B}_1)=0 \end{array}
ight.$ $egin{aligned} egin{aligned} egin{aligned\\ egin{aligned} egi$

其中 $\sigma = \sigma_f + \sigma_P$, α -自由电流面密度, α_M -磁化电流面密度

 $oldsymbol{e}_n\cdot(oldsymbol{J}_2-oldsymbol{J}_1)=-rac{\partial\sigma}{\partial t}$

能量守恒定律 $-\oint_S m{S} \cdot dm{\sigma} = \int_V m{f} \cdot m{v} dV + \frac{d}{dt} \int_V w dV$ 或 $-\nabla \cdot m{S} = \frac{\partial w}{\partial t} + m{f} \cdot m{v}$ 其中w-能量密度 S-能流密度(坡印廷矢量) f-场对电荷作用力密度 v-电荷速度

能流密度 $m{S} = m{E} imes m{H}$ 能量密度变化率 $rac{\partial w}{\partial t} = m{E} \cdot rac{\partial m{D}}{\partial t} + m{H} \cdot rac{\partial m{B}}{\partial t}$ 真空中 $S = \frac{1}{\mu_0} \mathbf{E} \times \mathbf{B}, w = \frac{1}{2} (\varepsilon_0 E^2 + \frac{1}{\mu_0} B^2)$

线性介质中(包含极化能和磁化能,不计介质热损耗) $w = \frac{1}{2}(\boldsymbol{E} \cdot \boldsymbol{D} + \boldsymbol{H} \cdot \boldsymbol{B})$

$$\frac{Q}{r'}) = \frac{1}{4\pi\varepsilon_0}[Q/\sqrt{x^2+y^2+(z-a)^2} - Q/\sqrt{x^2+y^2+(z+a)^2}]$$

真空中一半径为 R_0 的接地导体球,距球心 $a(>R_0)$ 处有一点电荷Q,镜像电荷 $Q'=-rac{R_0}{a}Q$ 位于距球心 $b=rac{R_0^2}{a}$ 处 格林函数法 给定区域V内电荷密度 $ho(oldsymbol{x}')$ 和边界条件,泊松方程的解为

 $\varphi(\mathbf{z}) = \textstyle \int_{V} G(\mathbf{z'},\mathbf{z}) dV' + \varepsilon_0 \oint_{S} [G(\mathbf{z'},\mathbf{z}) \frac{\partial \varphi}{\partial n'} - \varphi(\mathbf{z'}) \frac{\partial G(\mathbf{z'},\mathbf{z})}{\partial n'}] dS'$ 其中格林函数G(x',x)是该问题边界条件下格林方程 $\nabla^2 G(x',x) = -\frac{\delta(x-x')}{\xi_0}$ 的解

第1类边界条件 $G(\boldsymbol{x'},\boldsymbol{x})|_{\boldsymbol{x'} \in S} = 0$ 下 $\varphi(\mathbf{x}) = \int_{V} G(\mathbf{x}', \mathbf{x}) \rho(\mathbf{x}') dV' - \varepsilon_{0} \oint_{S} [\varphi(\mathbf{x}') \frac{\partial G(\mathbf{x}', \mathbf{x})}{\partial n'}] dS'$ 第2类边界条件 $\frac{\partial G(\mathbf{x}',\mathbf{x})}{\partial n'}$ $|_{\mathbf{x}' \in S} = -\frac{1}{\varepsilon_0 S}$ 下, $\varphi(\mathbf{x}) = \int_V G(\mathbf{x}',\mathbf{x}) \rho(\mathbf{x}') dV'$ $+\varepsilon_0$ $\oint_S G(x',x) \frac{\partial \varphi}{\partial n'} dS' + < \varphi>_S$ 其中< $\varphi>_S$ 为界面电势平均值

电荷体系电势多级展开式 $\varphi({m x})=rac{1}{4\piarepsilon_0}[rac{q}{R}+rac{{m p}\cdot{m R}}{R^3}+rac{1}{6}\sum_{i,j=1}^3\mathcal{D}rac{\partial^2}{\partial x_i\partial x_j}rac{1}{R}+\cdots]$ 其中电单极矩 $q=\int_V
ho(m{x}')dV'$,电偶极矩 $m{p}=\int_V
ho(m{x}')m{x}'dV'$

电四极矩 $\mathcal{D}_{ij}=\int_{V}3x_{i}^{\prime}x_{j}^{\prime}\rho(\boldsymbol{x}^{\prime})dV^{\prime}$

产生电势分别为 $\varphi^{(0)}(\boldsymbol{x}) = \frac{q}{4\pi\varepsilon_0 R}, \varphi^{(1)} = \frac{\boldsymbol{p} \cdot \boldsymbol{R}}{4\pi\varepsilon_0 R^3}, \varphi^{(2)}(\boldsymbol{x}) =$ $\frac{1}{24\pi\varepsilon_0}\sum_{i,j=1}^3 \mathcal{D}_{ij} \frac{\partial^2}{\partial x_i \partial x_j} \frac{1}{R}$ 当电荷分布中心对称, $\mathbf{p} = 0$,当反对称, $\mathcal{D} = 0$

静电场总能量(线性介质) $W=\frac{1}{2}\int_{\infty}m{E}\cdotm{D}dV=\frac{1}{2}\int_{V}
ho\varphi dV=\frac{1}{8\pi\varepsilon}\int dV\int dV'\frac{
ho(m{x})
ho(m{x}')}{r}$ 电势为 φ_e 的外场对电荷体系的作用能 $W=\int_V
ho(m{x}) \varphi_e(m{x}) dV = q \varphi_e(0) + m{p} \cdot \nabla \varphi_e(0) +$ $\frac{1}{6} \sum_{i,j=1}^{3} \mathcal{D}_{ij} \frac{\partial^{2}}{\partial x_{i} \partial x_{j}} \varphi_{e}(0) + \cdots$ 其中 $\varphi_{e}(0)$ 为外场在原点的电势

外场对电荷体系作用能 $W=\int_V
ho(m{x}) arphi_e(m{x}) dV$ 外场对电偶极子作用能 $W^{(1)}=m{p}\cdot
abla arphi_e=-m{p}\cdot m{E}_e$

外场对电偶极子作用力 $F = -\nabla W^{(1)} = p \cdot \nabla E_e$

外场对电偶极子力矩 $L_{ heta} = -rac{\partial W^{(1)}}{\partial heta} = oldsymbol{p} imes oldsymbol{E}_e$

外场对电四极矩作用能 $W^{(2)} = -\frac{1}{6} \sum_{i,j=1}^{3} \mathcal{D}_{ij} \frac{\partial^2}{\partial x_i \partial x_j} \mathbf{E}_e$

磁矢势多级展开式 $m{A}(m{x}) = rac{\mu_0}{4\pi} \int_V m{J}(m{x}') [rac{1}{R} - m{x}' \cdot
abla rac{1}{R} + \cdots] dV'$ 其中无磁单极矩 $\int_V m{J}(m{x}) dV' = 0, m{A}^{(1)} = 0$

磁偶极矩 $m{m} = rac{1}{2} \int_V m{x}' imes m{J}(m{x}') dV' = rac{I}{2} \oint_L m{x}' imes dm{l}' = I \Delta m{S}$

磁偶极矩产生的矢势 $m{A}^{(1)}=rac{\mu_0}{4\pi}rac{m{m} imesm{R}}{R^3}$

磁偶极矩产生的磁场 $m{B}(m{x}) =
abla imes m{A}^{(1)} = rac{\mu_0}{4\pi} [rac{3(m{m}\cdotm{R})m{R}}{D^5} - rac{m{m}}{D^3}]$ 静磁场总能量 $W=\int_{\infty} \frac{1}{2} {m B} \cdot {m H} dV = \int_{V} {m A} \cdot {m J} dV ($ 后者仅需对电流分布区域积分)

外磁场对电流作用能(不考虑电磁感应 $)W=\int_V oldsymbol{J}(oldsymbol{x})oldsymbol{A}_e(oldsymbol{x})dV$

外场对磁偶极子作用能 $W^{(1)} = -\boldsymbol{m} \cdot \boldsymbol{B}_e$

外场对磁偶极子作用力 $oldsymbol{F} = abla W^{(1)} = oldsymbol{m} \cdot
abla oldsymbol{B}_e$

外场对磁偶极子力矩 $m{L} = m{m} imes m{B}_e$

$$\begin{cases} \frac{E'}{E} = \frac{\sqrt{\varepsilon_1}\cos\theta - \sqrt{\varepsilon_2}\cos\theta''}{\sqrt{\varepsilon_1}\cos\theta + \sqrt{\varepsilon_2}\cos\theta''} = -\frac{\sin(\theta - \theta'')}{\sin(\theta + \theta'')} \\ \frac{E''}{E} = \frac{2\sqrt{\varepsilon_1}\cos\theta}{\sqrt{\varepsilon_1}\cos\theta + \sqrt{\varepsilon_2}\cos\theta''} = \frac{2\cos\theta\sin\theta''}{\sin(\theta + \theta'')} \end{cases}$$
对 $E \parallel \lambda \text{射面}(p \parallel \overline{k}) E \cos\theta - E' \cos\theta = E'' \cos\theta'', H + H' = H''$

 $\Rightarrow \sqrt{\varepsilon_1(E+E')} = \sqrt{\varepsilon_2}E''$ 结合折射定律得 $\frac{E'}{E} = \frac{\tan(\theta-\theta'')}{\tan(\theta+\theta'')}, \frac{E''}{E} = \frac{2\cos\theta\sin\theta''}{\sin(\theta+\theta'')\cos(\theta-\theta'')}$ 反射系数 $R_s = \frac{E'^2_s}{E_s^2} = \frac{\sin^2(\theta-\theta'')}{\sin^2(\theta+\theta'')}, R_p = \frac{E'^2_p}{E_p^2} = \frac{\tan^2(\theta-\theta'')}{\tan^2(\theta+\theta'')}$

当正入射 $\theta=0$, $R_s=R_p=(\frac{n_2-n_1}{n_2+n_1})^2$ 无损耗时, R+T=1

折射系数 $T_s = \frac{E_s''^2\sqrt{\varepsilon_2\cos\theta''}}{E_s^2\sqrt{\varepsilon_1\cos\theta}} = \frac{\sin 2\theta\sin 2\theta''}{\sin^2(\theta+\theta'')}, T_p = \frac{E_p''^2\sqrt{\varepsilon_2\cos\theta''}}{E_p^2\sqrt{\varepsilon_1\cos\theta}} = \frac{4\sin 2\theta\sin 2\theta''}{(\sin 2\theta+\sin 2\theta'')^2}$

布儒斯特角满足 $\theta + \theta'' = 90^{\circ}, \tan \theta_B = \frac{n_2}{n_1}$,此时p偏振无反射

当光密入射光疏介质 $n_{21} < 1$, θ 大于临界角 $\sin \theta_c = n_{21}$,全反射,折射波电场 $E'' = E''_0 e^{-\kappa z} e^{i(k''_x x - \omega t)}$ 共中 $k''_x = k_x = k \sin \theta$, $k''_z = \sqrt{k'''_2 - k''_x''_2} = ik\sqrt{\sin^2 \theta - n_{21}^2} = i\kappa$ 此时 $\frac{E'}{E} = \frac{\cos\theta - i\sqrt{\sin^2\theta - n_{21}^2}}{\cos\theta + i\sqrt{\sin^2\theta - n_{21}^2}} = e^{-2i\phi}$, $\tan\phi = \frac{\sqrt{\sin^2\theta - n_{21}^2}}{\cos\theta}$ 折射波平均能流密

 $\mathcal{E}\bar{S}_{x}^{\prime\prime} = \frac{1}{2}\text{Re}(E_{s}^{\prime\prime*}H_{z}^{\prime\prime}) = \frac{1}{2}\sqrt{\frac{\varepsilon_{2}}{\mu_{2}}}|E_{0}^{\prime\prime}|^{2}e^{-2\kappa z}\frac{\sin\theta}{n_{21}}, \bar{S}_{z}^{\prime\prime} = -\frac{1}{2}\text{Re}(E_{s}^{\prime\prime*}H_{x}^{\prime\prime}) = 0$

导体内 $rac{\partial
ho}{\partial t}=abla\cdot m{J}=-rac{\sigma}{arepsilon}
ho\Rightarrow
ho=
ho_0e^{-rac{\sigma}{arepsilon}t}$,特征时间 $au=rac{arepsilon}{\sigma}$,若 $\omega\ll au^{-1}$,视为良导体 $\nabla \times \mathbf{E} = i\omega \mu \mathbf{H}$ 引入复电容率 $\varepsilon' = \varepsilon + i \frac{\sigma}{\omega}$

良导体内麦氏方程组 $\nabla \times \mathbf{H} = -i\omega \varepsilon \mathbf{E} + \sigma \mathbf{E}$ 有 $\nabla \times \mathbf{H} = -i\omega \varepsilon' \mathbf{E}$ $\nabla \cdot \mathbf{E} = 0$ 且各反、折射规律与前同 $\nabla \cdot \mathbf{H} = 0$

反射和折射定律 $\theta=\theta', \frac{\sin\theta}{\sin\theta''}=\frac{\hat{n}_2}{n_1}, \hat{n}_2=c\sqrt{\mu_0\varepsilon'}=n+i\kappa$ $E_x = A_1 \cos k_x x \sin k_y y e^{ik_z z}$ 其中 $n^2 = \frac{c^2}{2} \left[\sqrt{\varepsilon^2 + (\frac{\sigma}{\omega})^2} + \varepsilon \right], \kappa^2 = \frac{c^2}{2} \left[\sqrt{\varepsilon^2 + (\frac{\sigma}{\omega})^2} - \varepsilon \right]$ $E_z = A_3 \sin k_x x \sin k_y y e^{ik_z z}$ 实折射角Re(θ'') = $\tan^{-1}\left[\frac{n_1\sin\theta}{q(n\cos\gamma-\kappa\sin\gamma)}\right]$, 衰减深度 $2\frac{\omega}{c}q(\kappa\cos\gamma+n\sin\gamma)$ 其中 $q^2\cos2\gamma=1-\frac{n^2-\kappa^2}{(n^2+\kappa^2)^2}(n_1\sin\theta)^2, q^2\sin2\gamma=\frac{2n\kappa}{(n^2+\kappa^2)^2}(n_1\sin\theta)^2$ $k_x A_1 + k_y A_2 - i k_z A_3 = 0$ (m,n)型波的**截止频率** $\omega_{c,mn}=\frac{\pi}{\sqrt{\mu\varepsilon}}\sqrt{(\frac{m}{a})^2+(\frac{n}{b})^2}$,超过则 k_z 为虚数,振幅沿z衰减 反射系数 $R_s = \left| \frac{\sin(\theta - \theta'')}{\sin(\theta - \theta'')} \right|^2, R_p = \left| \frac{\tan(\theta - \theta'')}{\tan(\theta + \theta'')} \right|^2$ 等离子体内外电荷分布 $\rho_e(\boldsymbol{x})$ 产生电势 $\varphi(\boldsymbol{x}) = \int \frac{\rho_e(\boldsymbol{x})}{4\pi\varepsilon_0|\boldsymbol{x}-\boldsymbol{x}'|} e^{-|\boldsymbol{x}-\boldsymbol{x}'|} dV'$ 当垂直入射 $R_s = R_p =$ $|\frac{\hat{n}_2 - n_1}{\hat{n}_2 + n_1}|^2 = \frac{(n - n_1)^2 + \kappa^2}{(n + n_1)^2 + \kappa^2} \qquad \text{ 折射波电场} \boldsymbol{E}(\boldsymbol{x}, t) = \boldsymbol{E}_0 e^{-\frac{\omega}{c} \kappa z + i \frac{\omega}{c} nz - i\omega t}$ 在屏蔽长度 $\lambda = \sqrt{\frac{kT\varepsilon_0}{n_0e^2}}$ 外可忽略,其中 n_0 为在 $\varphi(x) = 0$ 热平衡下电子密度 射频谐振腔 在导体表面仅需考虑 $m{e}_n imes m{E} = 0, m{e}_n imes m{H} = m{lpha}$ 再由 $abla \cdot m{E} = 0$ 得 $rac{\partial E_n}{\partial n} = 0$ 等离子体振荡 $\frac{\partial n}{\partial t} + \nabla \cdot (n \boldsymbol{v}) = 0, m \frac{d \boldsymbol{v}}{dt} = m (\frac{\partial \boldsymbol{v}}{\partial t} + \boldsymbol{v} \nabla \cdot \boldsymbol{v}) = -e \boldsymbol{E}, \nabla \cdot \boldsymbol{E} = -\frac{(n - n_0)e}{\varepsilon_0}$ 矩形谐振腔 分离变量得E或H的任一正交分量u(x,y,z)=设 $n' = n - n_0$ 和 \boldsymbol{v} 为一阶小量后有 $\frac{\partial n'}{\partial t} + n_0 \nabla \cdot \boldsymbol{v} = 0, \frac{\partial \boldsymbol{v}}{\partial t} = -\frac{e}{m} \boldsymbol{E}, \nabla \cdot \boldsymbol{E} = -\frac{e}{\varepsilon} n'$ $(C_1\cos k_xx+D_1\sin k_xx)(C_2\cos k_yy+D_2\sin k_yy)(C_3\cos k_zz+D_3\sin k_zz)$ $n'(t)=n'(0)e^{i\omega_p t}$,其中振荡频率 $\omega_p=\sqrt{rac{n_0e^2}{m_earepsilon_0}},m$ 为电子质量(忽略阻尼) $E_x = A_1 \cos k_x x \sin k_y y \sin k_z z$ $E_y = A_2 \sin k_x x \cos k_y y \sin k_z z \qquad \text{if} \qquad k_y = \frac{n\pi}{L_2} m, n, p = 0, 1, \cdots$ 电磁波在等离子体中的传播 $\frac{\partial \pmb{v}}{\partial t} = -\frac{e}{m}(\pmb{E}_i + \pmb{E}_e')$,因 $\nabla \pmb{E}_e = 0$,内场 \pmb{E}_i 引起的振荡同前 $k_z = \frac{p\pi}{L_3}$ 外场下 $\frac{\partial J}{\partial t} = \frac{n_0 e^2}{m} \boldsymbol{E}_e$,设 $\boldsymbol{E}(\boldsymbol{x},t) = \boldsymbol{E}(\boldsymbol{x}) e^{-i\omega t}$,欧姆定律 $\boldsymbol{J}(\omega) = \sigma(\omega) \boldsymbol{E}_e$ $E_z = A_3 \sin k_x x \sin k_y y \cos k_z z$ $k_x A_1 + k_y A_2 + k_z A_3 = 0$ 其中虚数电导率 $\sigma(\omega)=i\frac{n_0e^2}{m\omega}$,有效电容率 $\varepsilon'=\varepsilon-i\frac{\sigma}{\omega}$,波数 $k=\omega\sqrt{\mu_0\varepsilon'}=$ 本征频率 $\omega_{mnp} = \frac{\pi}{\sqrt{\mu\varepsilon}} \sqrt{\left(\frac{m}{L_1}\right)^2 + \left(\frac{n}{L_2}\right)^2 + \left(\frac{p}{L_3}\right)^2}$ $\frac{\omega}{c}\sqrt{1-(\omega_p/\omega)^2}$,折射率 $n=\sqrt{1-(\omega_p^2/\omega^2)^2}$ (忽略阻尼和外磁场作用) 矩形波导 分离变量 $u(x,y,z)=X(x)Y(y)e^{ik_{z}z}, \frac{d^{2}X}{dx^{2}}+k_{x}^{2}X=0, \frac{d^{2}Y}{dx^{2}}+k_{y}^{2}Y=0$ 平均辐射能流 $ar{S}=rac{c}{2\mu_0}(m{B}^*\cdotm{B})m{e}_R=rac{\mu_0\,\omega^4\,m_0^2}{32\pi^2\,c^3R^2}\sin^2 hetam{e}_R$ Chap5电磁波的辐射 平均辐射功率 $\bar{P} = \frac{\mu_0 \omega^4 m_0^2}{12\pi c^3}$ 电磁场 $m{B} =
abla imes m{A}, m{E} = abla arphi - rac{\partial m{A}}{\partial t}$ 经规范变换 $m{A} o m{A}' = m{A} +
abla \psi, arphi o arphi' = arphi - rac{\partial \psi}{\partial t}$ 不 规范 对 ∇A 的选择 库伦规范 $\nabla A = 0$ 洛伦兹规范 $\nabla \cdot A + \frac{1}{c^2} \frac{\partial \varphi}{\partial t} = 0$ 电四极辐射场 $m{A} = -rac{ik\mu_0e^{ikR}}{24\pi R}\dot{m{\mathcal{D}}} = rac{\mu_0e^{ikR}}{24\pi cR}\ddot{m{\mathcal{D}}}$ 其中 $m{\mathcal{D}} = e_R \cdot \ddot{m{\mathcal{D}}}$ 适用于一般规范的方程组 $\left\{ \begin{array}{l} \nabla^2 \boldsymbol{A} - \frac{1}{c^2} \frac{\partial^2 \boldsymbol{A}}{\partial t^2} - \nabla (\nabla \cdot \boldsymbol{A} + \frac{1}{c^2} \frac{\partial \varphi}{\partial t}) = -\mu_0 \boldsymbol{J} \\ \nabla^2 \varphi + \frac{\partial}{\partial t} \nabla \cdot \boldsymbol{A} = -\frac{\rho}{\varepsilon_0} \end{array} \right.$ $m{B} = rac{\mu_0 e^{ikR}}{24\pi c^2 R} \stackrel{...}{\mathcal{D}} imes m{e}_R, m{E} = cm{B} imes m{e}_R$ 库仑规范下化为 $\left\{ \begin{array}{l} \nabla^2 \boldsymbol{A} - \frac{1}{c^2} \frac{\partial^2 \boldsymbol{A}}{\partial t^2} - \frac{1}{c^2} \frac{\partial}{\partial t} \nabla \varphi = -\mu_0 \boldsymbol{J} \\ \nabla^2 \varphi = -\frac{\rho}{\varepsilon_0} \end{array} \right.$ 平均辐射能流 $\frac{c}{2\mu_0}(m{B}^*\cdotm{B})m{e}_R=\frac{\mu_0}{4\pi}\frac{1}{288\pi c^3R^2}(\dddot{\mathcal{D}} imesm{e}_R)^2m{e}_R$ 平均辐射功率 $\bar{P} = \frac{\mu_0}{4\pi} \frac{1}{360c^3} \sum_{i,j=1}^{3} |\ddot{\mathcal{D}}_{ij}|^2$ 库仑规犯下化力 $\nabla^2 \varphi = -\frac{\rho}{\varepsilon_0}$ 洛伦兹规范下为达朗贝尔方程 $\begin{cases} \nabla^2 \mathbf{A} - \frac{1}{c^2} \frac{\partial^2 \mathbf{A}}{\partial t^2} = -\mu_0 \mathbf{J} \\ \nabla^2 \varphi - \frac{1}{c^2} \frac{\partial^2 \varphi}{\partial t^2} = -\frac{\rho}{\varepsilon_0} \end{cases}$ 其解为 短天线辐射 $I(z)=I_0(1-\frac{2}{l}|z|), |z|\leq \frac{l}{2}\ll \lambda$ 电偶极变化率 $\dot{m p}=\int_{-l/2}^{l/2}m I(z)dz=\frac{1}{2}I_0m l$ 功率 $P = \frac{\mu_0 I_0^2 \omega^2 t^2}{48\pi c} = \frac{\pi}{12} \sqrt{\frac{\mu_0}{\varepsilon_0}} I_0^2 (\frac{l}{\lambda})^2 = \frac{1}{2} R_r I_0^2$ 辐射电阻 $R_r = \frac{\pi}{6} \sqrt{\frac{\mu_0}{\varepsilon_0}} (\frac{l}{\lambda})^2$

天线辐射 $I(z)=I_0\sin k(\frac{l}{2}-|z|)=(\stackrel{\centerdot}{=}l=\frac{\lambda}{2})I_0\cos kz, |z|\leq \frac{l}{2}\sim \lambda$ 推迟势 $m{A}(m{x},t) = rac{\mu_0}{4\pi} \int_V rac{J(m{x}',t-r/c)}{r} dV', \ \varphi(m{x},t) = rac{1}{4\piarepsilon_0} \int_V rac{
ho(m{x}',t-r/c)}{r} dV'$ 辐射场 $\boldsymbol{A}(\boldsymbol{x}) = \frac{\mu_0}{4\pi} \int_{\lambda/4}^{\lambda/4} \frac{e^{ikr}}{r} I_0 \cos kz dz = \frac{\mu_0 I_0 e^{ikR}}{2\pi kR} \frac{\cos(\frac{\pi}{2}\cos\theta)}{\sin^2\theta} e_z$ 其中 $r = |\boldsymbol{x} - \boldsymbol{x}'|$,若 $\boldsymbol{J}(\boldsymbol{x}', t) = \boldsymbol{J}(\boldsymbol{x}')e^{-i\omega t}$,则

能流密度 $\bar{S} = \frac{1}{2} \operatorname{Re}(\boldsymbol{E}^* \times \boldsymbol{H}) = \frac{\mu_0 c I_0^2}{8\pi^2 R^2} \frac{\cos^2(\frac{\pi}{2} \cos \theta)}{\sin^2 \theta} \boldsymbol{e}_R$,角分布 $\frac{\cos^2(\frac{\pi}{2} \cos \theta)}{\sin^2 \theta}$ 功率 $P = \oint |\bar{S}| R^2 d\Omega = \frac{\mu_0 c I_0^2}{4\pi} \int_0^{\pi} \frac{\cos^2(\frac{\pi}{2} \cos \theta)}{\sin \theta} d\theta$ ${m A}({m x},t) = {m A}({m x})e^{-i\omega t}, {m A}({m x}) = \frac{\mu_0}{4\pi}\int_V \frac{{m J}({m x}')e^{ikt}}{r}dV'$ 当 $l \ll \lambda, l \ll r$, 分3类 (1)近区 $r \ll \lambda, kr \ll 1 \Rightarrow e^{ikr} \ll 1$ 近似恒定场; (2)感应区 $r \sim \lambda$,过渡区域; (3) 遠区 $r \gg \lambda \Rightarrow r \approx R - e_R \cdot x', A(x) = \frac{\mu_0}{4\pi} \int_V \frac{J(x')e^{ik(R - e_R \cdot x')}}{R - e_R \cdot x'} dV', B =$

电磁波衍射 任一分量满足 $(\nabla^2+k^2)\varphi=0$ 用格林函数法 $(\nabla^2+k^2)G=-4\pi\delta({m x}-{m x}')$ 本基尔霍夫公式 $\varphi(x)=-\frac{1}{4\pi}\oint_S \frac{e^{ikr}}{r}\mathbf{e}_n\cdot \left[\nabla'\varphi(x')+(ik-\frac{1}{r})\frac{r}{r}\varphi(x')\right]dS'$ 未费小利符制 $\varphi(x)=\frac{i\varphi_0e^{ikR}}{r}$ $abla imes A pprox ike_R imes A, E = cB imes e_R, R$ 由坐标原点至场点,近似辐射场辐射场多级展开式(远区) $A(oldsymbol{x}) = rac{\mu_0 e^{ikR}}{4\pi R} \int_V oldsymbol{J}(oldsymbol{x}') [1 - ike_R \cdot oldsymbol{x}' + \cdots] dV'$ 夫琅禾费小孔衍射 $\varphi(\mathbf{x}) = -\frac{i\varphi_0 e^{ikR}}{4\pi R}\int_{S_0} e^{i(\mathbf{k}_1 - \mathbf{k}_2)\cdot\mathbf{x}'}(\cos\theta_1 + \cos\theta_2)dS'$

首项-电偶极 $m{p} = m{p}_0 e^{ikR}$ 辐射场 $m{A} = \frac{\mu_0 e^{ikR}}{4\pi R} \dot{m{p}}, m{B} = ik m{e}_R imes m{A} = \frac{e^{ikR}}{4\pi \varepsilon_0 c^3 R} \ddot{m{p}} imes m{e}_R$ 其中 φ —入射波振幅,R—孔心距场点, S_0 —孔面积, ${f x}'$ —孔上任一点, ${f \theta}_{1/2}$ —孔前/后波矢 ${f k}_{1/2}$ 与孔面法线夹角

 $m{E} = cm{B} imes m{e}_R = rac{e^{ikR}}{4\piarepsilon_0 c^2 R} (m{\ddot{p}} imes m{e}_R) imes m{e}_R$ 电磁场动量密度 $oldsymbol{g}=arepsilon_0oldsymbol{E} imesoldsymbol{B}=rac{oldsymbol{S}}{c^2}=rac{w}{c}oldsymbol{e}_k$ 平均辐射能流 $\bar{S} = \frac{1}{2} \operatorname{Re}(\vec{E^* \times H}) = \frac{c}{2\mu_0} \operatorname{Re}[(B^* \times e_R) \times B] = \frac{c}{2\mu_0} (B^* \cdot B) e_R =$ 动量流密度 $\overset{\vec{r}}{\mathcal{T}} = -\varepsilon_0 E E - \frac{1}{\mu_0} B B + \frac{1}{2} (\varepsilon_0 E^2 + \frac{1}{\mu_0} B^2) \overset{\vec{r}}{\mathcal{I}} = ($ 真空中 $) cg e_k e_k = w e_k e_k$ $\frac{\mu_0\omega^4 p_0^2}{32\pi^2cR^2}\sin^2\theta e_R,\sin^2\theta$ -角分布因子 平均辐射功率 $ar{P}=\oint_S ar{S}\cdot R^2d\Omega e_R=rac{\mu_0\omega^4 p_0^2}{12\pi c}$ 动量守恒定律 $\int_V {m f} dV + rac{d}{dt} \int_V {m g} dV = - \int_V \cdot \overset{
ightarrow}{\mathcal{T}} dV = - \oint_S d{m S} \cdot \overset{
ightarrow}{\mathcal{T}}$ 或 ${m f} + rac{\partial {m g}}{\partial t} = -
abla \cdot \overset{
ightarrow}{\mathcal{T}}$

第2项=磁偶极+电四极辐射,磁偶极 $m=m_0e^{-i\omega t}$ 辐射场 $\mathbf{A}=\frac{ik\mu_0e^{ikR}}{4\pi R}\mathbf{e}_R\times\mathbf{m}$ $\mathbf{B}=ik\mathbf{e}_R\times\mathbf{A}=\frac{\mu_0e^{ikR}}{4\pi c^2R}(\ddot{m}\times\mathbf{e}_R)\times\mathbf{e}_R, \mathbf{E}=c\mathbf{B}\times\mathbf{e}_R=-\frac{\mu_0e^{ikR}}{4\pi cR}\ddot{m}\times\mathbf{e}_R$ 辐射压强(完全反射) $P=-oldsymbol{e}_n\cdot \vec{\mathcal{T}}=2ar{w}_i\cos^2 heta$ 其中 w_i -入射波能量密度,heta-入射角

Chap6狭义相对论

相对论基本原理 1. 相对性原理 所有参考系均等价,物理规律对所有惯性系均为相同形式

2. 光速不变原理 真空中光速对任一惯性系沿任一方向恒为c

间隔不变性 惯性系 Σ 中任意两事件 (x_1,y_1,z_1,t_1) 和 (x_2,y_2,z_2,t_2) 的间隔为 $s^2=c^2(t_2-t_2)$ $(x_1)^2 - (x_2 - x_1)^2 - (y_2 - y_1)^2 - (z_2 - z_1)^2$

惯性系 Σ' 中对应两事件 (x_1',y_1',z_1',t_1') 和 (x_2',y_2',z_2',t_2') 的间隔为 $s'^2=c^2(t_2'-t_1')^2-t_1'$ $(x_2' - x_1')^2 - (y_2' - y_1')^2 - (z_2' - z_1')^2$ $\boxed{\text{tif } s'^2 = s^2}$

洛伦茲变换 参考系 Σ' 相对 Σ 以v运动且两者x正向均沿v

相对论时空结构 1. $s^2 = 0$ 即r = ct, 类光间隔(光锥, 两事件可由光波联系)

2. $s^2 > 0$ 即r < ct, 类时间隔(光锥内,两事件可由低于光速的作用来联系 (a)上半光锥—绝对未来: (b)下半—过去) $3.\ s^2 < 0$ 即r > ct类空间隔(光锥外,两事件绝无联系) 对于给定两事件此种间隔分类不因参考系改变而改变

洛伦兹变换的四维形式 将三维空间坐标与时间虚数坐标统一为四维坐标

$$x_{\mu}=(\boldsymbol{x},ict)=(x_1,x_2,x_3,x_4)$$
,洛伦兹变换可表为 $x'_{\mu}=a_{\mu\nu}x_{\nu}$,其中

因有间隔不变性 $x'_{\mu}x'_{\mu} = x_{\mu}x_{\mu} = \text{const}$, 洛伦兹变换为正交变换 $a_{\mu\nu}a_{\mu\tau}$

洛伦兹标量(不变量) 在洛伦兹变换下不变 $\delta_{\nu\tau} \mathbb{H} a^T a = I$ 满足 $V_{\mu} = a_{\mu\nu}V_{\nu}$ 四维张量 满足 $T'_{\mu\nu} = a_{\mu\lambda}a_{\nu\tau}T_{\lambda\tau}$

间隔 $d(s^2)=-dx_\mu dx_\mu$ 和固有时(物体静止坐标系中测出的时间) $d au=rac{1}{c}ds$ 为洛伦兹标量 四维速度矢量 $U_{\mu} = \frac{dx_{\mu}}{d\tau} = \gamma_{\mu}(u_1, u_2, u_3, ic)$ 四维波矢量 $k_{\mu} = (\mathbf{k}, i \frac{\omega}{\epsilon})$

特殊洛伦兹变换下相对论多普勒效应和光行差公式 $\left\{ \begin{array}{l} \omega' = \omega \gamma (1 - \frac{v}{c}\cos\theta) \\ \tan\theta' = \frac{\sin\theta}{\gamma(\cos\theta - \frac{v}{c})} \end{array} \right.$

四维电流密度 $J_{\mu} = \rho_0 U_{\mu} = (\boldsymbol{J}, ic\rho)$ 四维势 $A_{\mu} = (\boldsymbol{A}, i\varphi/c)$ 协变标量算符 $\frac{\partial}{\partial x_{\mu}} \frac{\partial}{\partial x_{\mu}} = \nabla^2 - \frac{1}{c^2} \frac{\partial^2}{\partial t^2} = \partial_{\mu} \partial_{\mu}$ 协变矢量算符 $\frac{\partial}{\partial x_{\mu}}=(\nabla,\frac{1}{ic}\frac{\partial}{\partial t})=\partial_n$

电磁场张量
$$F_{\mu\nu}=\partial_{\mu}A_{\nu}-\partial_{\nu}A_{\mu}=\left[egin{array}{cccc} 0 & B_3 & -B_2 & -iE_1/c \\ -B_3 & 0 & B_1 & -iE_2/c \\ B_2 & -B_1 & 0 & -iE_3/c \\ iE_1/c & iE_2/c & iE_3/c & 0 \end{array}
ight]$$

电荷守恒定律 $\partial_{\mu}J_{\mu}=0$ 洛伦兹规范 $\partial_{\mu}A_{\mu}=0$ 达朗贝尔方程 $\partial_{\nu}\partial_{\nu}A_{\mu}=-\mu_0J_{\mu}$ 麦克斯韦方程 $\partial_{\nu}F_{\mu\nu}=\mu_{0}J_{\mu},$ $\partial_{\lambda}F_{\mu\nu}+\partial_{\mu}F_{\nu\lambda}+\partial_{\nu}F_{\lambda\mu}=0$

能量动量守恒定律 $f_{\mu} = \partial_{\lambda} T_{\mu\lambda}$

电磁场变换关系
$$\begin{cases} E_{\parallel}' = E_{\parallel} & E_{\perp}' = \gamma (E + v \times B)_{\perp} \\ B_{\parallel}' = B_{\parallel} & B_{\perp}' = \gamma (B - \frac{v}{c^2} \times E)_{\perp} \end{cases}$$

洛伦兹不变量 $\frac{1}{2}F_{\mu\nu}F_{\mu\nu}=B^2-\frac{1}{c^2}E^2=0, \frac{i}{8}\varepsilon_{\mu\nu\lambda\tau}F_{\mu\nu}F_{\lambda\tau}=\frac{1}{c}{m B}\cdot{m E}=0$

能量-动量四维矢量 $p_{\mu} = m_0 U_{\mu} = (\boldsymbol{p}, p_4) = (\gamma m_0 \boldsymbol{v}, ic\gamma m_0)$

动质量 $m=\gamma m_0$ 故相对论动量 $m{p}=\gamma m_0m{v}=mm{v}$,相对论能量 $W=\gamma m_0c^2=mc^2$ 能量、动量和质量关系式 $W^2=p^2c^2+m_0^2c^4$ 质能关系 $\Delta W=(\Delta M)c^2$

四维力矢量 $K_{\mu}=\frac{dp_{\mu}}{d\tau}=(\frac{d\boldsymbol{p}}{d\tau},\frac{i}{c}\frac{dW}{d\tau})=(\gamma \boldsymbol{F},\frac{i}{c}\gamma \boldsymbol{F}\cdot\boldsymbol{v})=(\boldsymbol{K},\frac{i}{c}\boldsymbol{K}\cdot\boldsymbol{v})$ 四维洛伦兹力密度 $f_{\mu}=\rho_0 F_{\mu\nu} U_{\nu}=F_{\mu\nu} J_{\nu}=({\pmb f},i{\pmb E}\cdot{\pmb J}/c)$

标量场的梯度无旋 $\nabla \times \nabla \varphi = 0$ 矢量场的旋度无源 $\nabla \cdot \nabla \times \mathbf{f} = 0$ $\nabla(\varphi\psi) = \varphi\nabla\psi + \psi\nabla\varphi$ $\mathbf{f} \cdot (\varphi \mathbf{f}) = (\nabla \varphi) \cdot \mathbf{f} + \varphi \nabla \cdot \mathbf{f}$ $\nabla \times (\varphi \mathbf{f}) = (\nabla \varphi) \times \mathbf{f} + \varphi \nabla \times \mathbf{f}$

$$\begin{split} \nabla \cdot (f \times g) &= (\nabla \times f) \cdot g - f \cdot (\nabla \times g) \\ \nabla \times (f \times g) &= (g \cdot \nabla) f + (\nabla \cdot g) f - (f \cdot \nabla) g - (\nabla \cdot f) g \\ \nabla (f \cdot g) &= f \times (\nabla \times g) + (f \cdot \nabla) g + g \times (\nabla \times f) + (g \cdot \nabla) f \\ \nabla \times (\nabla \times f) &= \nabla (\nabla \cdot f) - \nabla^2 f \end{split}$$

 $\mathbf{a} \times (\mathbf{b} \times \mathbf{c}) = \mathbf{b}(\mathbf{a} \cdot \mathbf{c}) - \mathbf{c}(\mathbf{a} \cdot \mathbf{b})$ 高斯定理 $\iint_{\partial V} \mathbf{E} \cdot d\mathbf{S} = \iiint_{\nabla} \cdot \mathbf{E} dV$ 格林定理 $\nabla \cdot (u \nabla v) = u \nabla \cdot \nabla v + (\nabla u) \cdot (\nabla v)$ 斯多克斯定理 $\oint_{\partial S} m{E} \cdot dm{l} = \iint_{S} (
abla imes m{E}) \cdot dm{S}$

	直角坐标系	柱坐标系	球坐标系
梯度▽f	$\frac{\partial f}{\partial x}\hat{x} + \frac{\partial f}{\partial y}\hat{y} + \frac{\partial f}{\partial z}\hat{z}$	$rac{\partial f}{\partial ho}\hat{ ho}+rac{1}{ ho}rac{\partial f}{\partial arphi}\hat{arphi}+rac{\partial f}{\partial z}\hat{z}$	$\frac{\partial f}{\partial r}\hat{r} + \frac{1}{r}\frac{\partial f}{\partial \theta}\hat{\theta} + \frac{1}{r\sin\theta}\frac{\partial f}{\partial \varphi}\hat{\varphi}$
散度▽ · A	$\frac{\partial A_x}{\partial x} + \frac{\partial A_y}{\partial y} + \frac{\partial A_z}{\partial z}$	$\frac{1}{\rho} \frac{\partial (\rho A_{\rho})}{\partial \rho} + \frac{1}{\rho} \frac{\partial A_{\varphi}}{\partial \varphi} + \frac{\partial A_{z}}{\partial z}$	$\frac{1}{r^2}\frac{\partial (r^2A_r)}{\partial r} + \frac{1}{r\sin\theta}\frac{\partial (A_\theta\sin\theta)}{\partial \theta} + \frac{1}{r\sin\theta}\frac{\partial A\varphi}{\partial \varphi}$
拉普拉斯算子▽ ²	$\frac{\partial^2}{\partial x^2} + \frac{\partial^2}{\partial y^2} + \frac{\partial^2}{\partial z^2}$	$\frac{\partial^2}{\partial \rho^2} + \frac{1}{\rho} \frac{\partial}{\partial \rho} + \frac{1}{\rho^2} \frac{\partial^2}{\partial \varphi^2} + \frac{\partial^2}{\partial z^2}$	$\frac{1}{r^2} \frac{\partial}{\partial r} (r^2 \frac{\partial}{\partial r}) + \frac{1}{r^2 \sin \theta} \frac{\partial}{\partial \theta} (\sin \theta \frac{\partial}{\partial \theta}) + \frac{1}{r^2 \sin \theta^2 \theta} \frac{\partial^2}{\partial \varphi^2}$